

	Type	Hits	Search Text	DBs	Time Stamp
40	BRS	2	streaming adj boron	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/05/04 14:14
41	BRS	47706	boron adj (ions ion) with target amps	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/05/04 14:14
42	BRS	1	boron adj (ions ion) with target and amps	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/05/04 14:14
43	BRS	36	boron adj (ions ion) with target	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/05/04 14:15
44	BRS	24	boron adj (ions ion) with target and current	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/05/04 14:16
45	BRS	8	boron adj (ions ion) with target and electric adj current	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/05/04 14:16
46	BRS	1	boron adj (ions ion) with target same electric adj current	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/05/04 14:15
47	BRS	1	boron adj (ions ion) with target and (ion ions) with electric adj current	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/05/04 14:16
48	BRS	1	boron adj (ions ion) with target and target with electric adj current	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/05/04 14:16

	Type	Hits	Search Text	DBs	Time Stamp
49	BRS	1	boron adj (ions ion) with target and electric adj current and vacuum	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/05/04 14:16
50	BRS	8	boron adj (ions ion) with target and current and vacuum	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/05/04 14:17
51	BRS	4	boron adj (ions ion) with target and current and vacuum same boron	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/05/04 14:17
52	BRS	4	boron adj (ions ion) with target and current and vacuum same boron adj (ion ions)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/05/04 14:21
53	BRS	1	boron adj (ions ion) with target and semiconductor adj silicon and doping and temperature and vacuum same boron adj (ion ions)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/05/04 14:22
54	BRS	0	boron adj (ions ion) with target with semiconductor adj silicon and doping and temperature and vacuum same boron adj (ion ions)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/05/04 14:22
55	BRS	0	boron adj (ions ion) with target with semiconductor adj silicon and temperature and vacuum same boron adj (ion ions)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/05/04 14:22

	Type	Hits	Search Text	DBs	Time Stamp
58	BRS	0	hiney.att. and "438"/\$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/05/22 12:40
59	BRS	6	((implant implanting implanted implantation) with boron and solid and ions and plasma).clm.	US-PGPUB	2006/05/22 13:05
60	BRS	4	((implant implanting implanted implantation) with boron and vacuum and ions and plasma).clm.	US-PGPUB	2006/05/22 13:06
61	BRS	9	((implant implanting implanted implantation) with boron and solid and (ions plasma)).clm.	US-PGPUB	2006/05/22 13:06
62	BRS	16	((implant implanting implanted implantation) with boron and vacuum and (ions plasma)).clm.	US-PGPUB	2006/05/22 13:08
63	BRS	1	((implant implanting implanted implantation) with boron with vacuum and (ions plasma)).clm.	US-PGPUB	2006/05/22 13:06
64	BRS	4	((implant implanting implanted implantation) with boron with solid and (ions plasma)).clm.	US-PGPUB	2006/05/22 13:06
65	BRS	1	((implant implanting implanted implantation) with boron and vacuum and (ions plasma) not (gas vapor)).clm.	US-PGPUB	2006/05/22 13:08

	Type	Hits	Search Text	DBs	Time Stamp
66	BRS	3	((implant implanting implanted implantation) with boron and solid and (ions plasma) not (gas vapor)).clm.	US-PGPUB	2006/05/22 13:09
67	BRS	1	((implant implanting implanted implantation) with boron with solid and (ions plasma) not (gas vapor)).clm.	US-PGPUB	2006/05/22 13:09
68	BRS	4	("5517084" "5558718").pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/05/30 10:40
69	BRS	3	("5517084" "5558718").pn. and vacuum	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/05/30 10:46
70	BRS	2	("5517084" "5558718").pn. and boron	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/05/30 10:46